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TI-36818

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				U.S. PATENT DOC	UMENTS		
F	Cita	U.S. Patent Doo	Kind Code <sup>2</sup>	Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc.	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
Exam. nitials*	Cite No.	Number	(if known)		(mm-dd-yyyy)		
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Exam. Initials*	Cite No.*	trictude name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the Item (book, magazine, journal, serial, symposium, catalog, etc.), date, pace(s), volume-issue number(s), publisher, city and/or country where published.						
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